



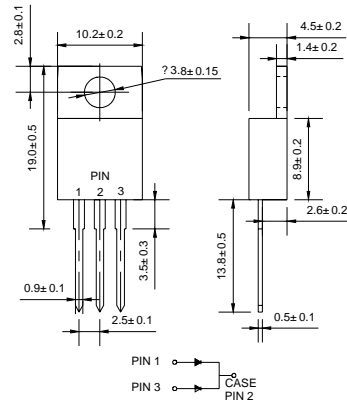
Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Glass passivated chip junction
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC TO-220AB
- ◇ Polarity: As marked
- ◇ Weight: 0.071 ounces, 2.006 gram
- ◇ Mounting position: Any

TO-220AB



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

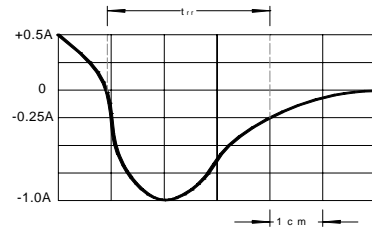
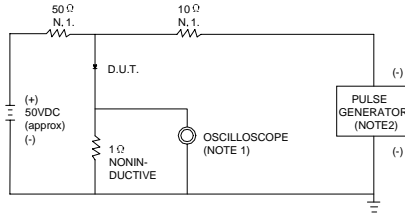
		UF 1010C	UF 1020C	UF 1030C	UF 1040C	UF 1060C	UF 1080C	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	100	200	300	400	600	800	V
Maximum RMS voltage	V_{RMS}	70	140	210	280	420	560	V
Maximum DC blocking voltage	V_{DC}	100	200	300	400	600	800	V
Maximum average forward rectified current @ $T_C=100^\circ\text{C}$	$I_{F(AV)}$	10						A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	125						A
Maximum instantaneous forward voltage @ 5.0A	V_F	1.0		1.3		1.7		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=125^\circ\text{C}$	I_R	10 500						μA
Maximum reverse recovery time (Note1)	t_{rr}	50				100		ns
Typical junction capacitance (Note2)	C_J	80				50		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	60						$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ----- + 150						$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ----- + 150						$^\circ\text{C}$

NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

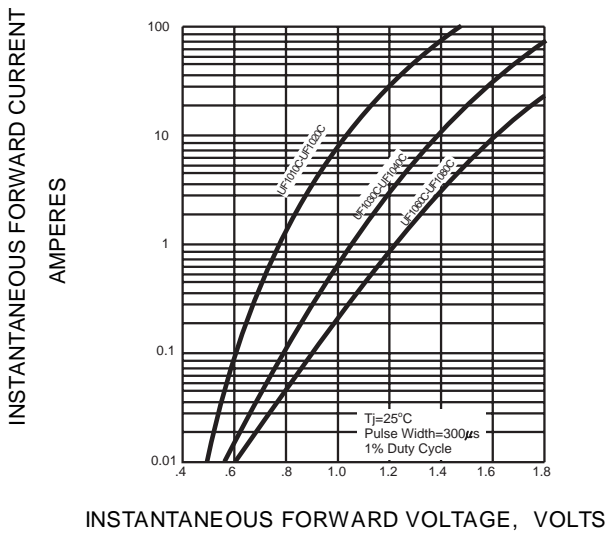
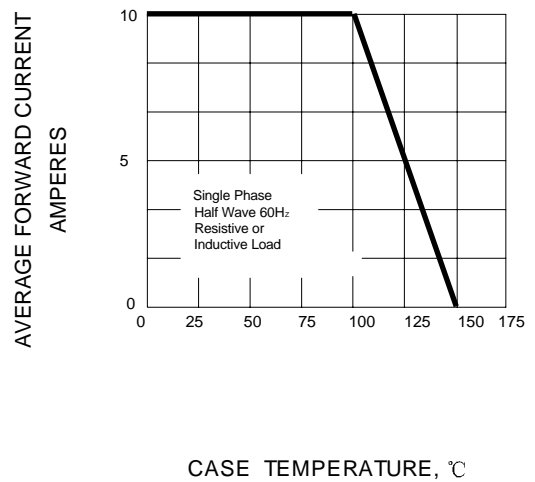
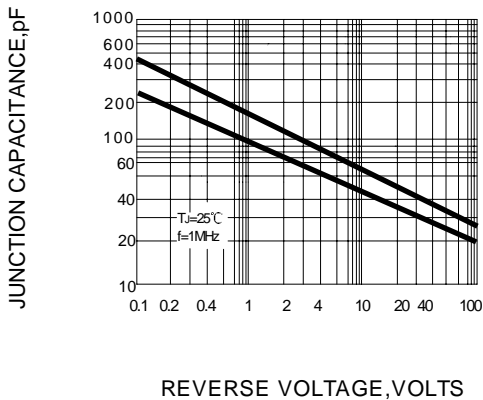
3. Thermal resistance junction to ambient

Ratings AND Characteristic Curves

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC


NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.
2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω .

SET TIME BASE FOR 10/20 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

FIG.3 -- FORWARD DERATING CURVE

FIG.4 -- TYPICAL JUNCTION CAPACITANCE

FIG.5 -- PEAK FORWARD SURGE CURRENT
